TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK118

General Purpose and Impedance Converter and Condenser Microphone Applications

• High breakdown voltage: $V_{GDS} = -50 \text{ V}$

• High input impedance: $I_{GSS} = -1$ nA (max) ($V_{GS} = -30$ V)

• Low noise: NF = 0.5dB (typ.) (RG = 100 k Ω , f = 120 Hz)

• Small package

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V_{GDS}	-50	V
Gate current	IG	10	mA
Drain power dissipation	P_{D}	100	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling

Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

0.55 MAX. 0.55 MAX. 0.55 MAX. 1.27 1.27 0.60 1. XVW 92 2. GATE 3. DRAIN JEDEC — JEITA — TOSHIBA 2-4E1B

Weight: 0.13 g (typ.)

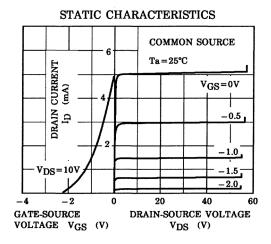
Electrical Characteristics (Ta = 25°C)

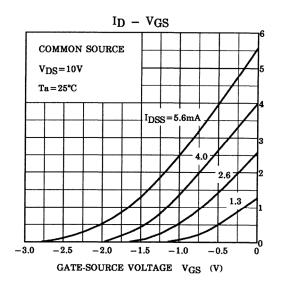
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = -30 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0$, $I_G = -100 \mu A$	-50	_	_	V
Drain current	I _{DSS} (Note)	V _{DS} = 10 V, V _{GS} = 0	0.3	_	6.5	mA
Gate-source cut-off voltage	V _{GS} (OFF)	$V_{DS} = 10 \text{ V}, I_D = 0.1 \mu A$	-0.4	_	-5.0	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	1.2	_	_	mS
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	8.2	_	pF
Reverse transfer capacitance	C _{rss}	$V_{GD} = -10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	2.6	_	pF
Noise figure	NF	V_{DS} = 15 V, V_{GS} = 0, R_G = 100 k Ω , f = 120 Hz	ı	0.5	5.0	dB

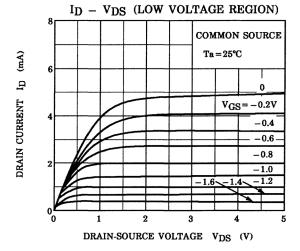
Note: I_{DSS} classification R: 0.3~0.75 mA, O: 0.6~1.4 mA, Y: 1.2~3.0 mA, GR: 2.6~6.5 mA

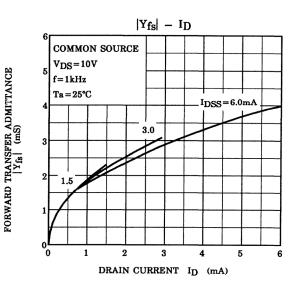
(mA)

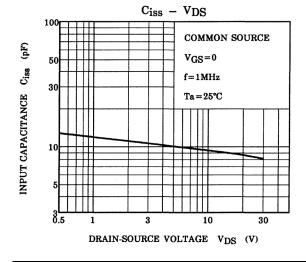
DRAIN CURRENT ID

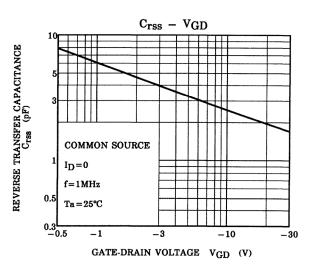






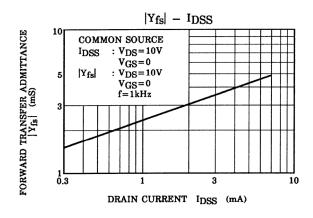


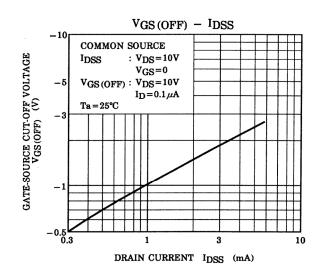


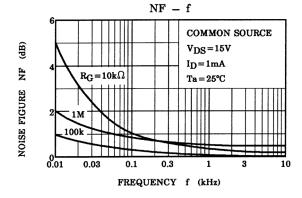


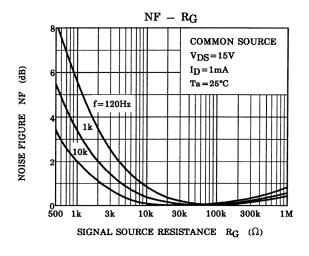
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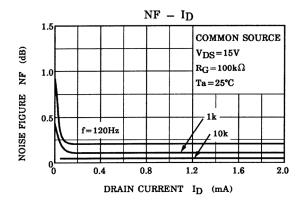
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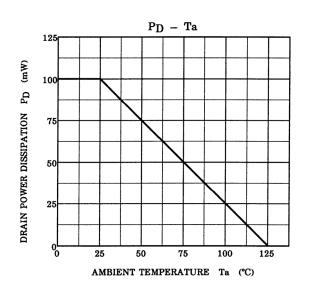




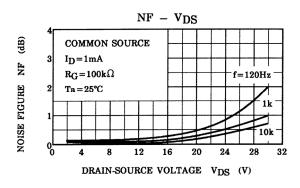








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20070701-EN GENERAL

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